

Substitute Form PTO-1449 (Modified) Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 10559-586002	Application No. 10/802,331
	Applicant Lawrence D. Wong		
	Filing Date March 16, 2004	Group Art Unit 2826	

U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
/S.R.W./	AA	7,030,468	04/18/2006	Gates et al.			
	AB						
	AC						

Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AD							
	AE							
	AF							

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
/S.R.W./	AG	Baklanov, M.R., et al., "Comparative study of Porous SOG Films with Different Non-Destructive Instrumentation", <i>Proceedings of the IEEE 2001 International Interconnect Technology Conference</i> , pp. 189-191, June 2001.
/S.R.W./	AH	Drage, J.S., et al., "Effects of Electron Beam Exposure on Poly(arylene Ether) Dielectric Films", <i>Mat. Res. Soc. Symp. Proc.: Low-Dielectric Constant Materials III</i> , vol. 476, pp. 121-128, April 1997.
/S.R.W./	AI	Feiler, D., et al., "E-Beam Curing Process of Low- κ Dielectrics for Unlabeled Vias in 0.25 μ m CMOS Technology", <i>Proc. 5th International Dielectrics for ULSI Multilevel Interconnection Conference (DUMIC)</i> , Catalog No. 99IMIC-44D, pp. 289-294, February 1999.
/S.R.W./	AJ	Kawamura, S., et al., "New Measurement Technique of Pore Size Distribution of Porous Low- κ Film", <i>Proceedings of the IEEE 2001 International Interconnect Technology Conference</i> , pp. 195-197, June 2001.
/S.R.W./	AK	Lee, H.-J., et al., "Characterization of Porous Low- κ Dielectric Thin Films Using X-Ray Reflectivity, Small Angle Neutron Scattering and Ion Scattering", <i>Proceedings of the IEEE 2001 International Interconnect Technology Conference</i> , pp. 247-249, June 2001.
/S.R.W./	AL	Lee, H.-J., et al., "A Novel and Low Thermal Budget Planarization Scheme for Pre-Metal Dielectric Using Electron-Beam Cured HSQ (Hydrogen Silsesquioxane) in STC (Stacked Capacitor) DRAM", <i>Extended Abstracts of the 1999 International Conference on Solid State Devices and Materials</i> , pp. 502-503, September 1999.
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Examiner Signature /Scott Wilson/	Date Considered 09/12/2008
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	